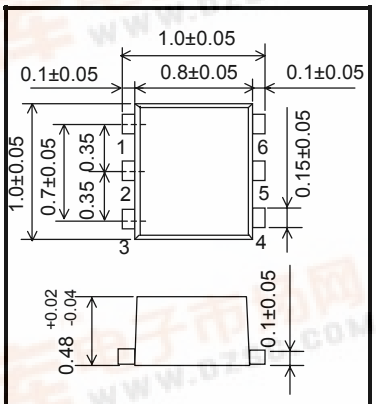
TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

HN2A26FS

Frequency General-Purpose Amplifier Applications

- Two devices are incorporated into a fine-pitch, Small-Mold (6-pin) package.
- High voltage: V_{CEO} = −50 V
- High current: I_C = −100 mA (max)
- High h_{FE}: h_{FE} = 120 to 400
- Excellent h_{FE} linearity
  : h_{FE} (I_C = −0.1 mA)/h_{FE} (I_C = −2 mA) = 0.95 (typ.)
- Lead (Pb) - free

Unit: mm



1. EMITTER1 (E1)
2. EMITTER2 (E2)
3. BASE2 (B2)
4. COLLECTOR2 (C2)
5. BASE1 (B1)
6. COLLECTOR1 (C1)

fS6

JEDEC	—
JEITA	—
TOSHIBA	2-1F1C

Weight: 0.001 g (typ.)

Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	−50	V
Collector-emitter voltage	V_{CEO}	−50	V
Emitter-base voltage	V_{EBO}	−5	V
Collector current	I_C	−100	mA
Base current	I_B	−30	mW
Collector power dissipation	P_C(Note)	50	mW
Junction temperature	T_j	150	°C
Storage temperature range	T_{stg}	−55 ~ 150	°C

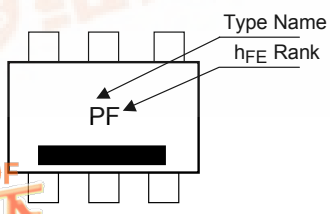
Note: Total rating.

Electrical Characteristics (Ta = 25°C)

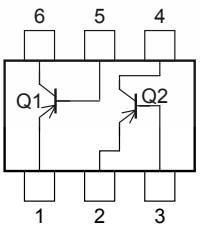
Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cutoff current	I_{CBO}	V_{CB} = −50 V, I_E = 0	—	—	−0.1	μA
Emitter cutoff current	I_{EBO}	V_{EB} = −5 V, I_C = 0	—	—	−0.1	μA
DC current gain	h_{FE}(Note)	V_{CE} = −6 V, I_C = −2 mA	120	—	400	
Collector-emitter saturation voltage	$V_{CE\ (sat)}$	I_C = −100 mA, I_B = −10 mA	—	−0.18	−0.3	V
Transition frequency	f_T	V_{CE} = −10 V, I_C = −1 mA	80	—	—	MHz
Collector output capacitance	C_{ob}	V_{CB} = −10 V, I_E = 0, f = 1 MHz	—	1.6	—	pF

Note: h_{FE} Classification Y (F): 120 ~ 140, GR (H): 200 ~ 400
( ) Marking symbol

Marking

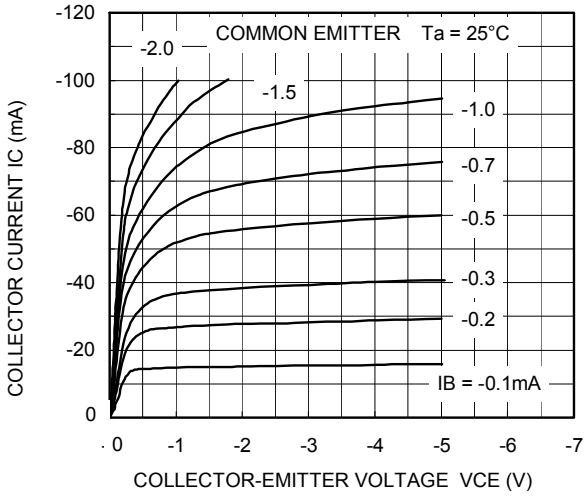


Equivalent Circuit (top view)

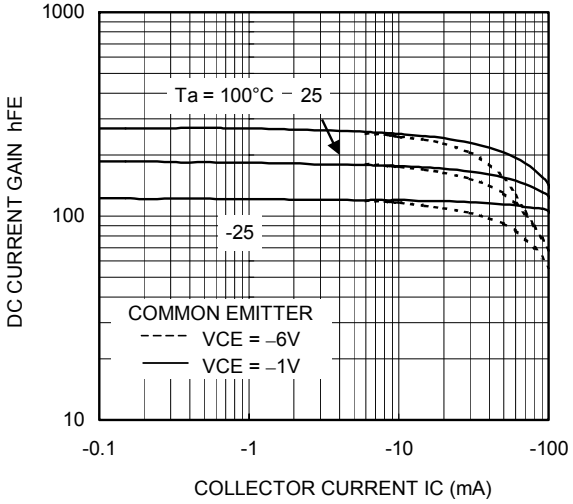


Q1, Q2 Common

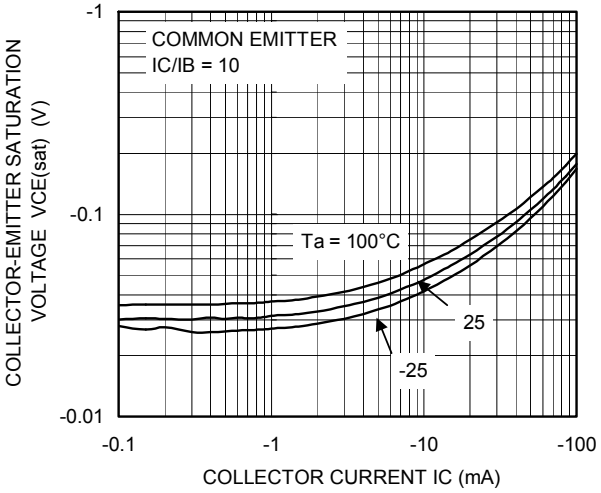
IC - VCE



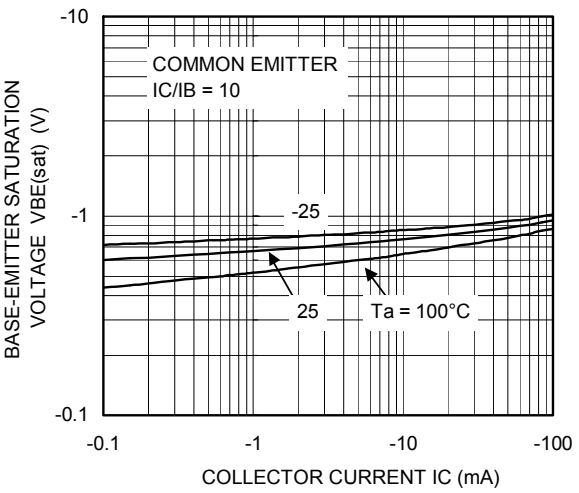
hFE - IC



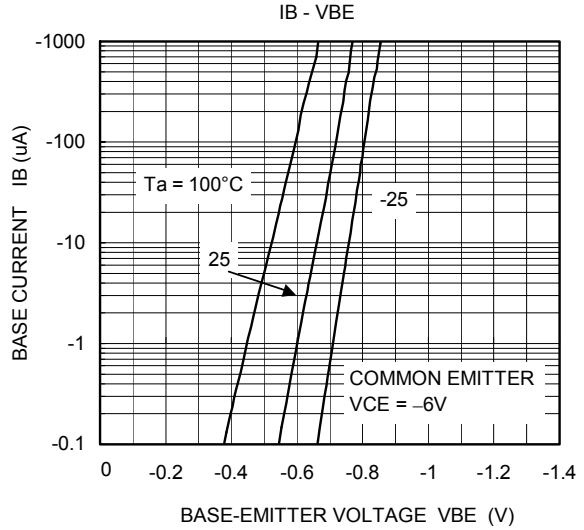
VCE(sat) - IC



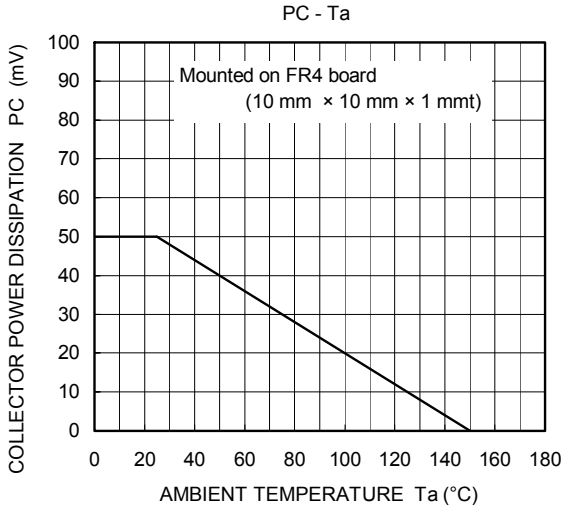
VBE(sat) - IC



IB - VBE



PC - Ta



*:Total rating.

RESTRICTIONS ON PRODUCT USE

030619EAA

- The information contained herein is subject to change without notice.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA for any infringements of patents or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of TOSHIBA or others.
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
  In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the “Handling Guide for Semiconductor Devices,” or “TOSHIBA Semiconductor Reliability Handbook” etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury (“Unintended Usage”). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer’s own risk.
- TOSHIBA products should not be embedded to the downstream products which are prohibited to be produced and sold, under any law and regulations.